



First Named Inventor	Kirk D. Prall
Serial No.	10/786,765
Filing Date	February 25, 2004
Group Art Unit	2848 2814
Examiner Name	Unknown HOAI PHAM
Confirmation No.	2857
Attorney Docket No.	400.266US01
Title: MULTI-LAYER MEMORY ARRAYS	

**SECOND SUPPLEMENTAL
INFORMATION DISCLOSURE
STATEMENT
FORM PTO-1449**

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Examiner Initials	Author, Title, Date, Pages, etc.

Examiner Signature	<i>Hoai Pham</i>	Date Considered	01/05/06
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*Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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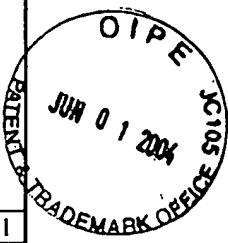
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